NSN 5961-01-326-7684

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-326-7684 **Inclosure Material:** Metal and glass **Overall Length:** 2.265 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Reverse polarity **Overall Width Across Flats:** 1.060 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1800.0 repetitive peak reverse voltage and 1900.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 90.00 amperes drain current universal and 275.00 amperes forward current, total rms horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No